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Correction to "Quantitative study of the energy changes in voltage-controlled spin crossover molecular thin films" [*The Journal of Physical Chemistry Letters* (2020) 11:19 (8231-8237) DOI: 10.1021/acs.jpclett.0c02209]

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Correction to "Quantitative Study of the Energy Changes in Voltage-Controlled Spin Crossover Molecular Thin Films"

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In our recent publication, Figure 5 was published without adequate due diligence. The correct TOC Abstract graphic and Figure 5 are contained here in this correction. The correct on to off current ratios are in the range of 4 to 5, not 100 and the signal to noise ratios are far less than previously shown.

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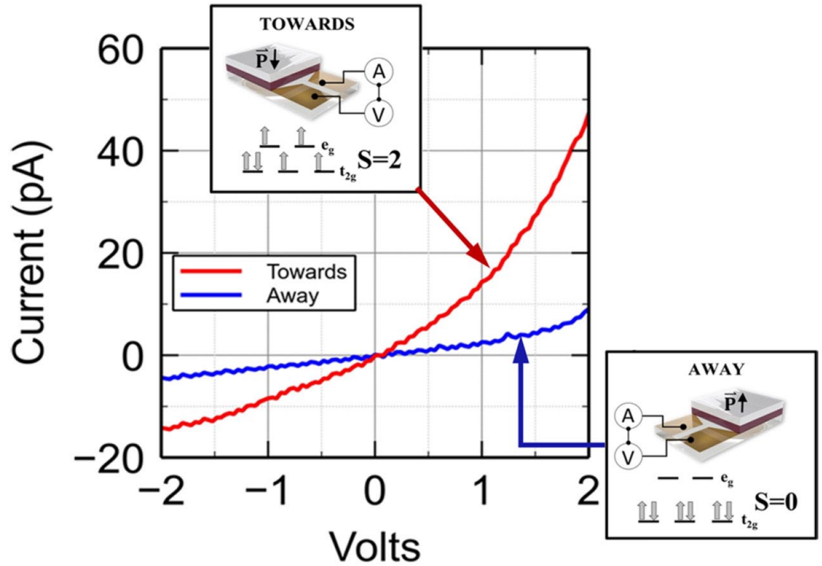

Figure 5. Change in conductance observed with different ferroelectric polarization directions. Transport measurements were taken across a device with the ferroelectric layer adjacent to the SCO layer. Polarizing the ferroelectric toward the [Fe{H2B(pz)2}2(bipy)] layer results in HS S = 2, and a larger conductance. Polarization of the ferroelectric away from the [Fe{H2B(pz)2}2(bipy)] layer gives the LS S = 0 state and lower conductance. Device type 3 is schematically illustrated.